

## Supporting information

### Fast, high chromatic, electrically responsive photonic crystal inks for displays

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**Table S1** Comparison of the various ERPCs in literature works and this work: the chemical composition, the working electric field, and the corresponding required time to shift 35nm from the initial state.

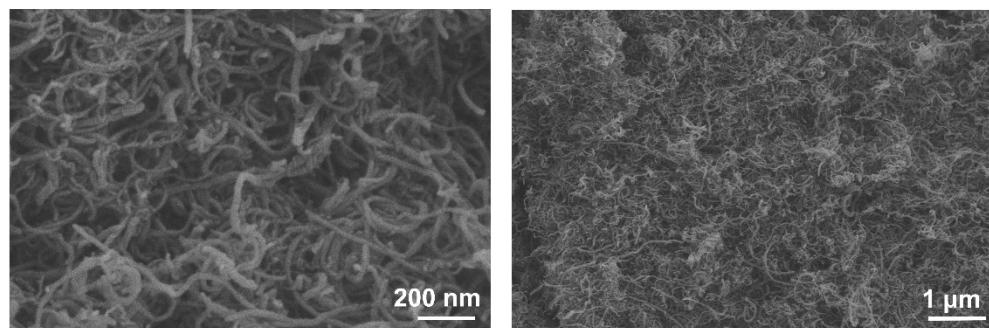
Particles <sup>a</sup>	d <sub>p</sub> (nm)	f <sub>p</sub> (%)	Solvent	E(10 <sup>4</sup> V/m)	U(V)	Thickness(μm)	Time(s)
PMMA-co-PS <sup>S1</sup>	137	/	H <sub>2</sub> O	2.50	2.5	100	80
SiO <sub>2</sub> <sup>S2</sup>	120	10	PCb	1.25	2.5	200	60
PS <sup>S3</sup>	138	/	H <sub>2</sub> O	/	AC	100	9
Fe <sub>3</sub> O <sub>4</sub> @C <sup>S4</sup>	130	18	PCb	2.70	2.7	100	60
SiO <sub>2</sub> <sup>S5</sup>	200	20	PCb	2.50	2.5	100	20
SiO <sub>2</sub> <sup>S6</sup>	171	18	aniline	1.00	1.0	100	10
SiO <sub>2</sub>	189	25	PCb	1.25	2.5	200	5

Note<sup>a</sup>: These f<sub>p</sub> values referred to the weight percentages of colloidal particles, and the data in the table corresponds to an electric field of 1.00-2.70\*10<sup>4</sup> V/m. Some particles in the literature can achieve faster response times under high electric field.

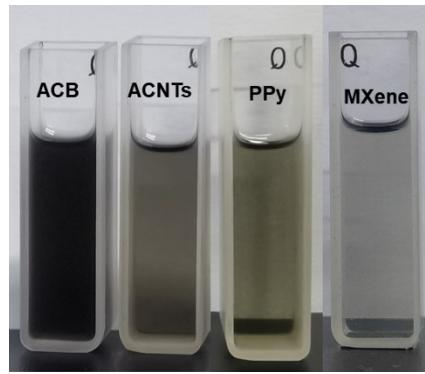
**Table S2** The recipes of the SiO<sub>2</sub> based liquid photonic crystals.

Sample <sup>b</sup>	SiO <sub>2</sub> (%)	SiO <sub>2</sub> ( $\mu$ L)	PC ( $\mu$ L)	Black (%)
A	15.0	30.0	170.0	0
B	20.0	40.0	160.0	0
C	25.0	50.0	150.0	0
D	30.0	60.0	140.0	0
E	25.0	50.0	150.0	0.025
F	25.0	50.0	150.0	0.050
G	25.0	50.0	150.0	0.100

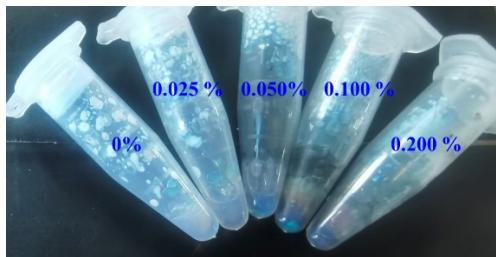
Note<sup>b</sup>: The density of SiO<sub>2</sub> microspheres is 2.0 g/cm<sup>3</sup>, the density of ethanol is 0.79 g/cm<sup>3</sup>, Black (%) refers to the mass percentage of black substance in SiO<sub>2</sub>



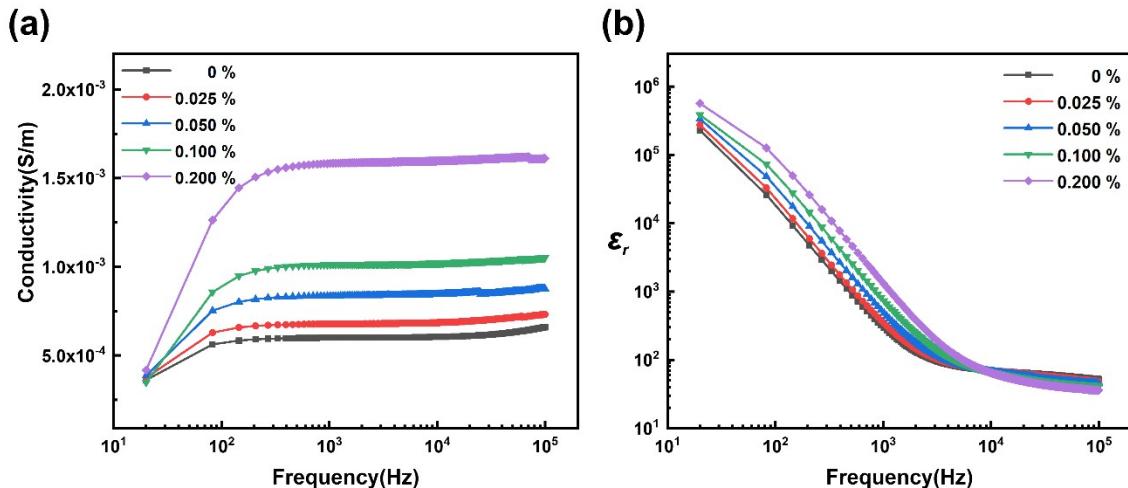
**Fig. S1.** SEM images of ACNTs.



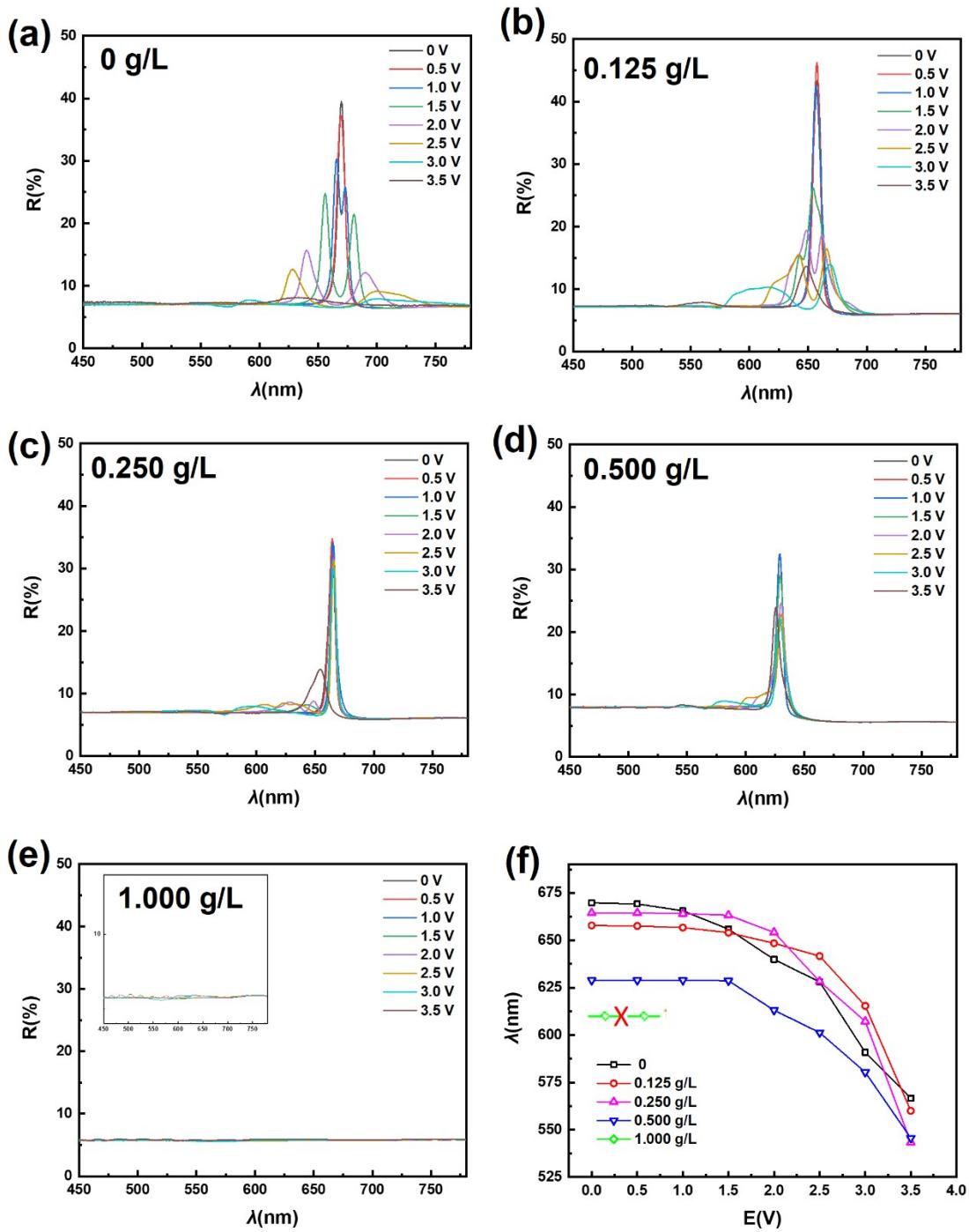
**Fig. S2.** Optical images of suspensions of four black substances (ACB, ACNTs, PPy and MXene) with mass fraction of 0.01% in ethanol.



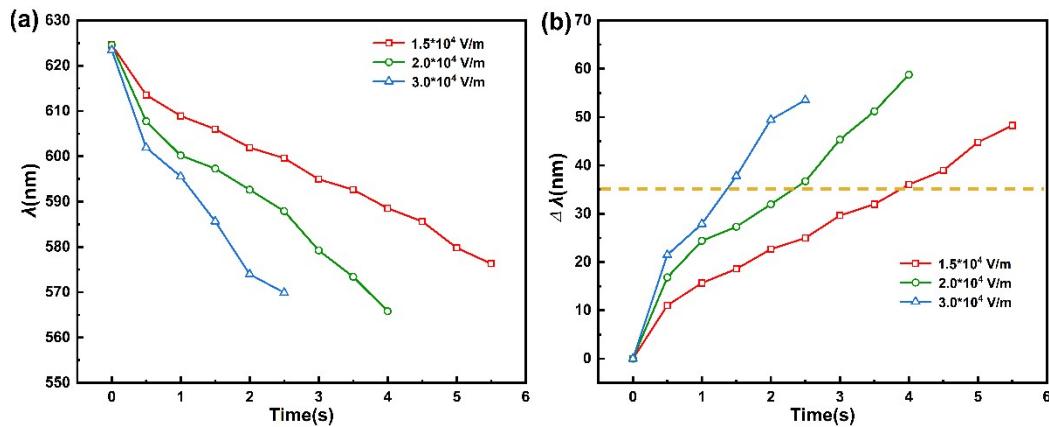
**Fig. S3.** Optical images of  $\text{SiO}_2$  based liquid photonic crystals (LPCs) with different contents of ACNTs.



**Fig. S4.** (a) Conductive spectra of  $\text{SiO}_2$  based LPCs with different ACNTs additions; (b) relative dielectric constant spectra of  $\text{SiO}_2$  based LPCs with different ACNTs additions.



**Fig. S5.** Reflection spectra of  $\text{SiO}_2$  based ERPCs with different SDBS concentration as the electric field increases from 0 to 3.5 V: (a) 0 g/L, (b) 0.125 g/L, (c) 0.250 g/L, (d) 0.500 g/L, (e) 1.000 g/L; (f) the reflection wavelength of  $\text{SiO}_2$  based ERPCs with SDBS as the electric field increases from 0 to 3.5 V.



**Fig. S6.** The reflection wavelength changes of  $\text{SiO}_2$  based ERPCs with SDBS: when electric voltages of 3.0 V, 4.0 V and 6.0 V are applied (yellow dashed line as reference wavelength for comparison).

## References

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